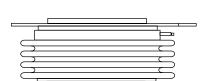


### Vishay High Power Products

# Phase Control Thyristors (Hockey PUK Version), 560 A



TO-200AC (B-PUK)

560 A

**PRODUCT SUMMARY** 

 $I_{\mathsf{T}(\mathsf{AV})}$ 

#### **FEATURES**

- · Center amplifying gate
- · Metal case with ceramic insulator
- International standard case TO-200AC (B-PUK)



• Designed and qualified for industrial level



ROHS

### TYPICAL APPLICATIONS

- DC motor controls
- · Controlled DC power supplies
- AC controllers

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	VALUES	UNITS			
1		560	Α			
I <sub>T(AV)</sub>	T <sub>hs</sub>	55	°C			
I <sub>T(RMS)</sub>		1115	A			
	T <sub>hs</sub>	25	°C			
1	50 Hz	8000	۸			
I <sub>TSM</sub>	60 Hz	8380	Α			
124	50 Hz	320	kA <sup>2</sup> s			
l <sup>2</sup> t	60 Hz	292	KA-S			
V <sub>DRM</sub> /V <sub>RRM</sub>		400 to 2000	V			
tq	Typical	100	μѕ			
T <sub>J</sub>		- 40 to 125	°C			

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS								
TYPE NUMBER	VOLTAGE CODE	V <sub>DRM</sub> /V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	$\begin{aligned} I_{DRM}/I_{RRM} & \text{MAXIMUM} \\ \text{AT T}_{J} &= T_{J} & \text{MAXIMUM} \\ \text{mA} \end{aligned}$				
	04	400	500					
	08	800	900					
ST300CL	12	1200	1300	50				
0100002	16	1600	1700	00				
	18	1800	1900					
	20	2000	2100					

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## ST300CLPbF Series

## Vishay High Power Products Phase Control Thyristors (Hockey PUK Version), 560 A



ABSOLUTE MAXIMUM RATIN	GS					
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average on-state current		180° condu	ction, half sine v	vave	560 (275)	Α
at heatsink temperature	I <sub>T(AV)</sub>	double side	(single side) co	oled	55 (75)	°C
Maximum RMS on-state current	I <sub>T(RMS)</sub>	DC at 25 °C	heatsink tempe	erature double side cooled	1115	
		t = 10 ms	No voltage		8000	
Maximum peak, one-cycle	<b>I</b>	t = 8.3 ms	reapplied		8380	A kA <sup>2</sup> s
non-repetitive surge current	I <sub>TSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>	Sinusoidal half wave, initial $T_J = T_J$ maximum	6730	
		t = 8.3 ms	reapplied		7040	
	l <sup>2</sup> t	t = 10 ms	No voltage reapplied		320	
Maximum I <sup>2</sup> t for fusing		t = 8.3 ms			292	
Maximum i-t for fusing		t = 10 ms			226	
		t = 8.3 ms	reapplied		207	
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 to 10 ms, no voltage reapplied			3200	kA²√s
Low level value of threshold voltage	V <sub>T(TO)1</sub>	(16.7 % x π	(16.7 % x $\pi$ x I <sub>T(AV)</sub> < I < $\pi$ x I <sub>T(AV)</sub> ), T <sub>J</sub> = T <sub>J</sub> maximum			V
High level value of threshold voltage	V <sub>T(TO)2</sub>	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			0.98	T V
Low level value of on-state slope resistance	r <sub>t1</sub>	(16.7 % x $\pi$ x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$ ), $T_J = T_J$ maximum			0.74	<b>m</b> 0
High level value of on-state slope resistance	r <sub>t2</sub>	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			0.73	mΩ
Maximum on-state voltage	$V_{TM}$	$I_{pk} = 1635 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sine pulse}$			2.18	V
Maximum holding current	I <sub>H</sub>	T 05 00 and a small 40 V model in lead		600	mA	
Typical latching current	Ι <sub>L</sub>	T <sub>J</sub> = 25 °C, anode supply 12 V resistive load			1000	IIIA

SWITCHING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 $\Omega$ , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%~V_{DRM}$	1000	A/µs		
Typical delay time	t <sub>d</sub>	Gate current 1 A, $dl_g/dt = 1$ A/ $\mu$ s $V_d = 0.67 \% V_{DRM}$ , $T_J = 25 °C$	1.0			
Typical turn-off time	tq	$I_{TM} = 550 \text{ A, } T_J = T_J \text{ maximum, dl/dt} = 40 \text{ A/}\mu\text{s,}$ $V_R = 50 \text{ V, dV/dt} = 20 \text{ V/}\mu\text{s, gate 0 V } 100 \Omega, t_p = 500 \mu\text{s}$	100	μs		

BLOCKING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 80 % rated $V_{DRM}$	500	V/µs		
Maximum peak reverse and off-state leakage current	I <sub>RRM,</sub> I <sub>DRM</sub>	$T_J = T_J$ maximum, rated $V_{DRM}/V_{RRM}$ applied	50	mA		





## Phase Control Thyristors Vishay High Power Products (Hockey PUK Version), 560 A

TRIGGERING						
DADAMETER	CVMDOL	SYMBOL TEST CONDITIONS		VALUES		што
PARAMETER	SYMBOL			TYP.	MAX.	UNITS
Maximum peak gate power	P <sub>GM</sub>	$T_J = T_J$ maximum,	$t_p \le 5 \text{ ms}$	10.0		w
Maximum average gate power	P <sub>G(AV)</sub>	$T_J = T_J$ maximum,	f = 50 Hz, d% = 50	2	.0	VV
Maximum peak positive gate current	I <sub>GM</sub>	$T_J = T_J$ maximum,	$t_p \leq 5 \text{ ms}$	3.	.0	Α
Maximum peak positive gate voltage	+ V <sub>GM</sub>			20		V
Maximum peak negative gate voltage	- V <sub>GM</sub>	$T_J = T_J$ maximum, $t_p \le 5$ ms			.0	]
		T <sub>J</sub> = - 40 °C	Maximum required gate trigger/ current/voltage are the lowest value which will trigger all units 12 V anode to cathode applied	200	-	mA V
DC gate current required to trigger	I <sub>GT</sub>	T <sub>J</sub> = 25 °C		100	200	
		T <sub>J</sub> = 125 °C		50	-	
		T <sub>J</sub> = - 40 °C		2.5	-	
DC gate voltage required to trigger	$V_{GT}$	T <sub>J</sub> = 25 °C		1.8	3.0	
		T <sub>J</sub> = 125 °C		1.1	-	
DC gate current not to trigger	I <sub>GD</sub>	T T maximum	Maximum gate current/ voltage not to trigger is the maximum value which will not	10.0		mA
DC gate voltage not to trigger	$V_{GD}$	$T_J = T_J$ maximum	trigger any unit with rated V <sub>DRM</sub> anode to cathode applied	0.25		V

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum operating junction temperature range	$T_J$		- 40 to 125	- °C		
Maximum storage temperature range	T <sub>Stg</sub>		- 40 to 150			
Maximum thermal resistance, junction to heatsink	D	DC operation single side cooled	0.11			
waximum thermal resistance, junction to heatslik	R <sub>thJ-hs</sub>	DC operation double side cooled	0.05	K/W		
Maximum thermal resistance, case to heatsink	R <sub>thC-hs</sub>	DC operation single side cooled	0.011	IV VV		
waximum thermal resistance, case to heatslink		DC operation double side cooled	0.006	]		
Mounting force, ± 10 %			9800 (1000)	N (kg)		
Approximate weight			250	g		
Case style		See dimensions - link at the end of datasheet	TO-200AC (	B-PUK)		

△R <sub>thJ-hs</sub> CONDUCTION							
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION		RECTANGULAR CONDUCTION		TEST CONDITIONS	UNITS	
CONDUCTION ANGLE	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE	SIDE TEST CONDITIONS		
180°	0.012	0.010	0.008	0.008	$T_J = T_J$ maximum	K/W	
120°	0.014	0.015	0.014	0.014			
90°	0.018	0.018	0.019	0.019			
60°	0.026	0.027	0.027	0.028			
30°	0.045	0.046	0.046	0.046			

#### Note

• The table above shows the increment of thermal resistance R<sub>thJ-hs</sub> when devices operate at different conduction angles than DC

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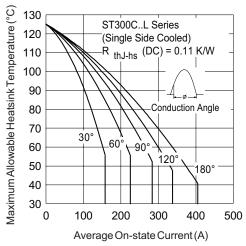


Fig. 1 - Current Ratings Characteristics

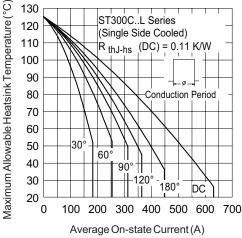


Fig. 2 - Current Ratings Characteristics

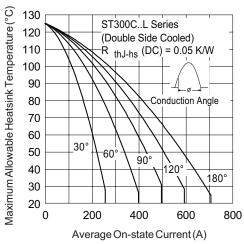


Fig. 3 - Current Ratings Characteristics

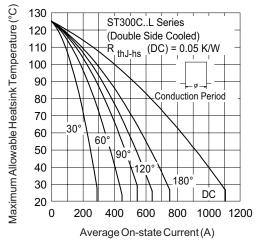


Fig. 4 - Current Ratings Characteristics

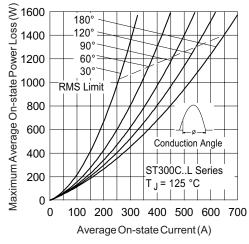


Fig. 5 - On-State Power Loss Characteristics

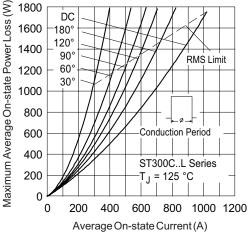


Fig. 6 - On-State Power Loss Characteristics



## Phase Control Thyristors Vishay High Power Products (Hockey PUK Version), 560 A

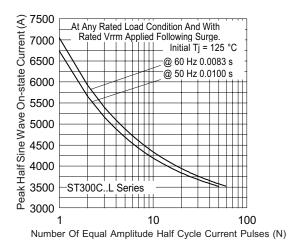


Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

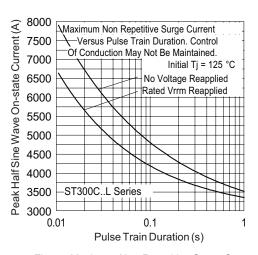


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

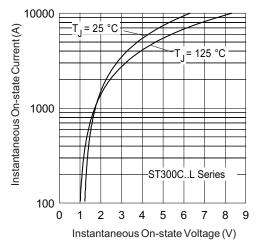


Fig. 9 - On-State Voltage Drop Characteristcs

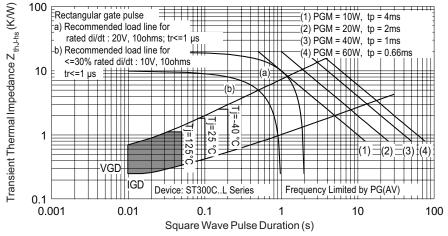


Fig. 10 - Thermal Impedance Z<sub>thJ-hs</sub> Characteristics

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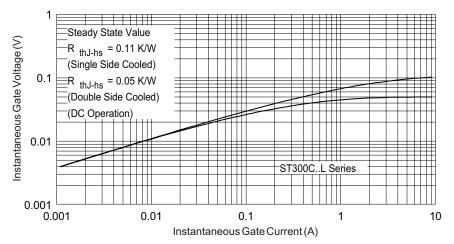
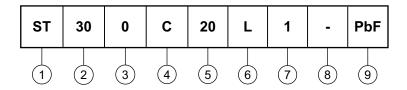


Fig. 11 - Gate Characteristics

#### **ORDERING INFORMATION TABLE**

**Device code** 



- 1 Thyristor
- 2 Essential part number
- 3 0 = Converter grade
- 4 C = Ceramic PUK
- 5 Voltage code x 100 = V<sub>RRM</sub> (see Voltage Ratings table)
- 6 L = PUK case TO-200AC (B-PUK)
- 7 0 = Eyelet terminals (gate and auxiliary cathode unsoldered leads)
  - 1 = Fast-on terminals (gate and auxiliary cathode unsoldered leads)
  - 2 = Eyelet terminals (gate and auxiliary cathode soldered leads)
  - 3 = Fast-on terminals (gate and auxiliary cathode soldered leads)
- 8 Critical dV/dt: None = 500 V/µs (standard selection)
  - L = 1000 V/µs (special selection)
- 9 Lead (Pb)-free

LINKS TO RELATED DOCUMENTS				
Dimensions	http://www.vishay.com/doc?95076			

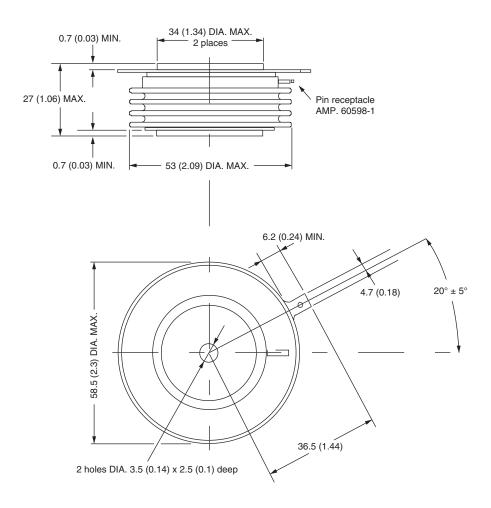


## Vishay Semiconductors

## **TO-200AC (B-PUK)**

#### **DIMENSIONS** in millimeters (inches)

Creepage distance: 36.33 (1.430) minimum Strike distance: 17.43 (0.686) minimum



Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)



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